Rydberg Photonics with Thin-Film Cuprous Oxide

Hadiseh Alaeian^{1,2}, Kinjol Barua¹, Arya Keni¹, Alexandra Boltasseva¹, and Valentin Walther^{2,3}

¹Elmore Family School of Electrical and Computer Engineering, Purdue University, West Lafayette 47906, USA.

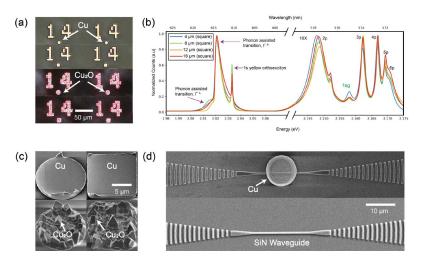
²Department of Physics and Astronomy, Purdue University, West Lafayette 47906, USA.

³Department of Chemistry, Purdue University, West Lafayette 47906, USA.

*e-mail: halaeian@purude.edu

Cuprous oxide (Cu₂O) has gained attention as a solid-state material with the potential for hosting excitonic Rydberg states. These states are defined by high principal quantum numbers (n), leading to significantly larger wavefunctions. As a result, Cu₂O exhibits strong dipole-dipole ($\propto n^4$) and van der Waals ($\propto n^{11}$) interactions, making it an attractive platform for solid-state quantum technologies. Thin-film Cu₂O samples are of particular interest as they can be meticulously fabricated to reduce defects, allowing for the observation of extreme single-photon nonlinearities via the Rydberg blockade.

In this presentation, I share our recent findings on the spectroscopic absorption and photoluminescence of Rydberg excitons in synthetic Cu_2O thin films. Our results show a series of yellow excitons extending up to a principal quantum number of n = 7. I discuss our progress in the bottom-up assembly of 2D arrays of Rydberg excitons, which could make a platform for simulating lattice models. Furthermore, I present promising results from coupling Rydberg excitons with silicon nitride photonic circuitry, marking a significant advancement in Rydberg photonics. Finally, I will cover our theoretical results on open quantum system phase transitions that can be explored using strongly interacting Rydberg polaritons. These discoveries pave the way for the development of scalable and integrated on-chip quantum devices based on Rydberg states in Cu₂O.



(a) site-selective growth of Cu_2O thin films. (b) PL spectrum of the fabricated array. (c) SEM image of the site-selective grown films. (d) Fabricated SiN waveguide integrated with Cu_2O .

References

[1] J. DeLange et al, Scientific Reports 13, 16881 (2023)

[2] H. Alaeian and V. Walther, arXiv 2311.15091 (2023)

Acknowledgments

This work was supported by the Purdue University Startup Fund, College of Science Quantum Initiative, and the Air Force Office of Scientific Research under award number FA9550-23-1-0489.